74LV4060

14-stage binary ripple counter with oscillator

Rev. 6 — 16 April 2024

Product data sheet

1. General description

The 74LV4060 is a 14-stage ripple-carry counter/divider and oscillator with three oscillator terminals (RS, R_{TC} and C_{TC}), ten buffered parallel outputs (Q₃ to Q₉ and Q₁₁ to Q₁₃) and an overriding asynchronous master reset (MR). The oscillator configuration allows design of either RC or crystal oscillator circuits. The oscillator may be replaced by an external clock signal at input RS. In this case, keep the oscillator pins (R_{TC} and C_{TC}) floating. The counter advances on the HIGH-to-LOW transition of RS. A HIGH level on MR clears all counter stages and forces all outputs LOW, independent of the other input conditions. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V_{CC}.

2. Features and benefits

- Wide supply voltage range from 1.0 V to 5.5 V
- Optimized for low voltage applications from 1.0 V to 3.6 V
- · CMOS low power dissipation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V; T_{amb} = 25 °C
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at V_{CC} = 3.3 V; T_{amb} = 25 °C
- · All active components on-chip
- RC or crystal oscillator configuration
- · Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

3. Applications

- Control counters
- Timers
- · Frequency dividers
- · Time-delay circuits

4. Ordering information

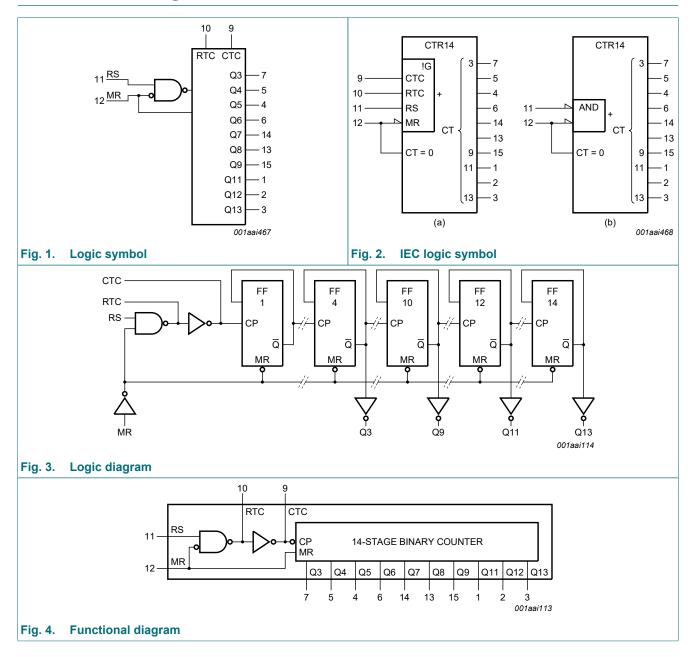
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LV4060D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74LV4060PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1



14-stage binary ripple counter with oscillator

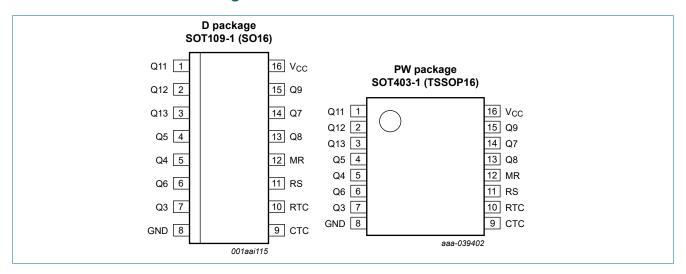
5. Functional diagram



14-stage binary ripple counter with oscillator

6. Pinning information

6.1. Pinning



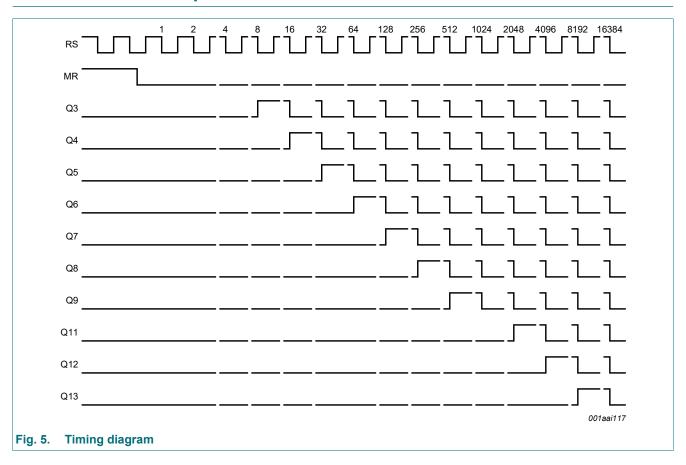
6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description		
Q11 to Q13	1, 2, 3	counter output		
Q3 to Q9	7, 5, 4, 6, 14, 13, 15	counter output		
GND	8	ground (0 V)		
СТС	9	external capacitor connection		
RTC	10	external resistor connection		
RS	11	clock input/oscillator pin		
MR	12	master reset		
V _{CC}	16	supply voltage		

14-stage binary ripple counter with oscillator

7. Functional description



8. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

0	B	O PC		D.4.		11.1.14
Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I _{OK}	output clamping current	V_{O} < -0.5 V or V_{O} > V_{CC} + 0.5 V	[1]	-	±50	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

14-stage binary ripple counter with oscillator

9. Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage	[1]	1.0	3.3	5.5	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.0 V to 2.0 V	-	-	500	ns/V
		V _{CC} = 2.0 V to 2.7 V	-	-	200	ns/V
		V _{CC} = 2.7 V to 3.6 V	-	-	100	ns/V
		V _{CC} = 3.6 V to 5.5 V	-	-	50	ns/V

^[1] The 74LV4060 is guaranteed to function down to V_{CC} = 1.0 V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2 V to V_{CC} = 5.5 V.

10. Static characteristics

Table 5. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level	MR input						
	input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		V _{CC} = 2.0 V	1.4	-	-	1.4	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	0.7V _{CC}	-	V
		RS input						
		V _{CC} = 1.2 V	1.0	-	-	1.0	-	V
		V _{CC} = 2.0 V	1.6	-	-	1.6	-	V
		V _{CC} = 2.7 V to 3.6 V	2.4	-	-	2.4	-	V
		V _{CC} = 4.5 V to 5.5 V	0.8V _{CC}	-	-	0.8V _{CC}	-	V
V _{IL}	LOW-level	MR input						
	input voltage	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
		V _{CC} = 2.0 V	-	-	0.6	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3V _{CC}	-	0.3V _{CC}	V
		RS input						
		V _{CC} = 1.2 V	-	-	0.2	-	0.2	V
		V _{CC} = 2.0 V	-	-	0.4	-	0.4	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.2V _{CC}	-	0.2V _{CC}	V

14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions	-40	-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max		
/он	HIGH-level	RTC output; RS = MR = GND							
	output voltage	V _{CC} = 1.2 V; I _O = -3.4 mA	-	-	-	-	-	٧	
		V _{CC} = 2.0 V; I _O = -3.4 mA	-	-	-	-	-	٧	
		V _{CC} = 2.7 V; I _O = -3.4 mA	-	-	-	-	-	٧	
		V _{CC} = 3.0 V; I _O = -3.4 mA	2.40	2.82	-	2.20	-	٧	
		V _{CC} = 4.5 V; I _O = -3.4 mA	-	-	-	-	-	٧	
		RTC output; RS = MR = V _{CC}							
		V _{CC} = 1.2 V; I _O = -0.8 mA	-	-	-	-	-	V	
		V _{CC} = 2.0 V; I _O = -0.8 mA	-	-	-	-	-	V	
		V _{CC} = 2.7 V; I _O = -0.8 mA	-	-	-	-	-	V	
		V _{CC} = 3.0 V; I _O = -0.8 mA	2.40	2.82	-	2.20	-	V	
	$V_{CC} = 2.$ $V_{CC} = 3.$ $V_{CC} = 4.$ HIGH-level output voltage $V_{CC} = 1.$ $V_{CC} = 2.$ $V_{CC} = 3.$ $V_{CC} = 3.$ $V_{CC} = 4.$ RTC output $V_{CC} = 1.$ $V_{CC} = 2.$ $V_{CC} = 2.$ $V_{CC} = 3.$ $V_{CC} = 3.$ $V_{CC} = 3.$ $V_{CC} = 4.$ CTC output	V _{CC} = 4.5 V; I _O = -0.8 mA	-	-	-	-	-	V	
/он	HIGH-level	RTC output; RS = MR = GND							
	output voltage	V _{CC} = 1.2 V; I _O = -100 μA	1.0	1.2	-	1.0	-	V	
		V _{CC} = 2.0 V; I _O = -100 μA	1.8	2.0	-	1.8	-	V	
		V _{CC} = 2.7 V; I _O = -100 μA	-	-	_	-	-	V	
		V _{CC} = 3.0 V; I _O = -100 μA	2.8	3.0	-	2.8	-	V	
		V _{CC} = 4.5 V; I _O = -100 μA	_	_	-	-	_	V	
		RTC output; RS = MR = V _{CC}							
		V _{CC} = 1.2 V; I _O = -100 μA	1.0	1.2	-	1.0	_	V	
		V _{CC} = 2.0 V; I _O = -100 μA	1.8	2.0	-	1.8	Max - V - V - V - V - V - V - V - V - V -	V	
		V _{CC} = 2.7 V; I _O = -100 μA	_	-	-	-	_		
		V _{CC} = 3.0 V; I _O = -100 μA	2.8	3.0	_	2.8	_	V	
		V _{CC} = 4.5 V; I _O = -100 μA	-	-	_	-	_	V	
		CTC output; RS = V _{IH} and MR = V _{IL}							
		V _{CC} = 1.2 V; I _O = -3.8 mA	_	1.2	_	_	_	V	
		V _{CC} = 2.0 V; I _O = -3.8 mA	_	_	_	_	_		
		V _{CC} = 2.7 V; I _O = -3.8 mA	_	_	_	_	_		
		V _{CC} = 3.0 V; I _O = -3.8 mA	2.40	2.82	_	2.20	_		
		V _{CC} = 4.5 V; I _O = -3.8 mA	-	-	_	-	_	V	
		except RTC output; V _I = V _{IH} or V _{IL}						-	
		V _{CC} = 1.2 V; I _O = -100 μA	1.0	1.2	-	1.0	_	V	
		V _{CC} = 2.0 V; I _O = -100 μA	1.8	2.0	_	1.8	_		
		V _{CC} = 2.7 V; I _O = -100 μA	-	-	_	-	_		
		V _{CC} = 3.0 V; I _O = -100 μA	2.8	3.0	_	2.8	_		
		V _{CC} = 4.5 V; I _O = -100 μA	-	-	_	-	_		
		except RTC and CTC outputs; V _I = V _{IH} or V _{IL}							
		V _{CC} = 1.2 V; I _O = -6 mA	_	_	_	_	_	V	
		$V_{CC} = 2.0 \text{ V}; I_{O} = -6 \text{ mA}$	_	_		_	_	V V V V V V V V V V V V V V V V V V V	
		$V_{CC} = 2.7 \text{ V}; I_0 = -6 \text{ mA}$	_	_		_			
		$V_{CC} = 3.0 \text{ V}; I_{O} = -6 \text{ mA}$	2.40				-		
		$V_{CC} = 3.0 \text{ V}; I_0 = -6 \text{ mA}$ $V_{CC} = 4.5 \text{ V}; I_0 = -6 \text{ mA}$	2.40	2.82	-	2.20	-		

14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions	-40	°C to +85	o °C	-40 °C to	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V _{OL}	LOW-level	RTC output; RS = V _{CC} and MR = GND						
	output voltage	V _{CC} = 1.2 V; I _O = -3.4 mA	-	-	-	-	-	V
		V _{CC} = 2.0 V; I _O = -3.4 mA	-	-	-	-	-	V
		V _{CC} = 2.7 V; I _O = -3.4 mA	-	-	-	-	-	V
		V _{CC} = 3.0 V; I _O = -3.4 mA	-	0.25	0.40	-	0.50	V
		V _{CC} = 4.5 V; I _O = -3.4 mA	-	-	-	-	-	V
V _{OL}	LOW-level	RTC output; RS = V _{CC} and MR = GND;						
	output voltage	V _{CC} = 1.2 V; I _O = -100 μA	-	0	0.2	-	0.2	V
		V _{CC} = 2.0 V; I _O = -100 μA	-	0	0.2	-	0.2	V
		V _{CC} = 2.7 V; I _O = -100 μA	-	-	-	-	-	V
		V _{CC} = 3.0 V; I _O = -100 μA	-	0	0.2	-	0.2	V
		V _{CC} = 4.5 V; I _O = -100 μA	-	-	-	-	-	V
		CTC output; RS = V _{IH} and MR = V _{IL} ;						
		V _{CC} = 1.2 V; I _O = -3.8 mA	-	-	-	-	-	٧
		V _{CC} = 2.0 V; I _O = -3.8 mA	-	-	-	-	-	V
		V _{CC} = 2.7 V; I _O = -3.8 mA	-	-	-	-	-	٧
		V _{CC} = 3.0 V; I _O = -3.8 mA	-	0.25	-	0.40	0.50	٧
		V _{CC} = 4.5 V; I _O = -3.8 mA	-	-	-	-	-	V
		except RTC output; V _I = V _{IH} or V _{IL} ;						
		V _{CC} = 1.2 V; I _O = -100 μA	-	0	0.2	-	0.2	V
		V _{CC} = 2.0 V; I _O = -100 μA	-	0	0.2	-	0.2	V
		V _{CC} = 2.7 V; I _O = -100 μA	-	-	-	-	-	٧
		V _{CC} = 3.0 V; I _O = -100 μA	-	0	0.2	-	0.2	V
		V _{CC} = 4.5 V; I _O = -100 μA	-	-	-	-	-	V
		except RTC and CTC output; V _I = V _{IH} or V _{IL}						
		V _{CC} = 1.2 V; I _O = -6 mA	-	-	-	-	-	V
		V _{CC} = 2.0 V; I _O = -6 mA	-	-	-	-	-	V
		V _{CC} = 2.7 V; I _O = -6 mA	-	0.25	0.40	-	0.50	V
		V _{CC} = 3.0 V; I _O = -6 mA	-	-	-	-	-	٧
		V _{CC} = 4.5 V; I _O = -6 mA	-	-	-	-	-	V
I	input leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{CC} \text{ or GND}$	-	-	1.0	-	1.0	μΑ
CC	supply current	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0 \text{ A}$	-	-	20	-	160	μA
-	-	$V_{CC} = 5.5 \text{ V}; V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A}$	-	-	-	-	80	μA
ΔI _{CC}	additional supply current	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}; V_{I} = V_{CC} - 0.6 \text{ V};$ $I_{O} = 0 \text{ A}$	-	-	500	-	850	μA
Cı	input capacitance		-	3.5	-	-	-	pF

^[1] All typical values are measured at T_{amb} = 25 °C.

14-stage binary ripple counter with oscillator

11. Dynamic characteristics

Table 6. Dynamic characteristics

GND = 0 V; for test circuit, see Fig. 9.

Symbol	Parameter	Conditions		-40	°C to +8	5°C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	RS to Q3; see Fig. 6 and Fig. 8	[2]						
		V _{CC} = 1.2 V		-	180	-	-	- 105 83 - 66 49 - 29 20 - 16 11 - 58 49 - 39 29	ns
		V _{CC} = 2.0 V		-	52	84	-	105	ns
		V _{CC} = 2.7 V		-	42	66	-	83	ns
		V _{CC} = 3.3 V; C _L = 15 pF		-	29	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	33	53	-	66	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	-	24	39	-	49	ns
		Qn to Qn+1; see Fig. 7 and Fig. 8							
		V _{CC} = 1.2 V		-	40	-	-	-	ns
		V _{CC} = 2.0 V		-	14	23	-	29	ns
		V _{CC} = 2.7 V		-	10	16	-	20	ns
		V _{CC} = 3.3 V; C _L = 15 pF		-	6	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	8	13	-	16	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	-	6	9	-	11	ns
t _{PHL} HIGH to L	HIGH to LOW	MR to Qn; see Fig. 7 and Fig. 8							
	propagation delay	V _{CC} = 1.2 V		-	100	-	-	-	ns
		V _{CC} = 2.0 V		-	29	46	-	58	ns
		V _{CC} = 2.7 V		-	24	39	-	11 r - r 58 r 49 r - r 39 r	ns
		V _{CC} = 3.3 V; C _L = 15 pF		-	16	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	19	31	-	39	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	-	14	23	-	29	ns
t _W	pulse width	RS HIGH or LOW; see Fig. 6							
		V _{CC} = 2.0 V		34	9	-	38	-	ns
		V _{CC} = 2.7 V		25	6	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	20	5	-	24	-	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	16	4	-	20	-	ns
		MR HIGH; see Fig. 8							
		V _{CC} = 2.0 V		34	10	-	38	-	ns
		V _{CC} = 2.7 V		25	8	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	16	4	-	20	-	ns
t _{rec}	recovery time	MR to RS; see Fig. 8							
		V _{CC} = 2.0 V		29	18	-	37	-	ns
		V _{CC} = 2.7 V		26	16	-	32	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	18	11	-	23	-	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	12	7	-	15	-	ns

Product data sheet

14-stage binary ripple counter with oscillator

Symbol	Parameter	Conditions		-40	0 °C to +85 °C		-40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
f _{max}	maximum	see Fig. 6							
	frequency	V _{CC} = 2.0 V		14	40	-	9	-	MHz
		V _{CC} = 2.7 V		19	70	-	12	-	MHz
		V _{CC} = 3.3 V; C _L = 15 pF		-	99	-	-	-	MHz
		V _{CC} = 3.0 V to 3.6 V	[3]	24	90	-	15	-	MHz
		V _{CC} = 4.5 V to 5.5 V	[4]	30	100	-	19	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[5]	-	40	-	-	-	pF

- All typical values are measured at T_{amb} = 25 °C.
- t_{pd} is the same as t_{PLH} and t_{PHL} . Typical value measured at V_{CC} = 3.3 V. [3]
- Typical value measured at $V_{CC} = 5.0 \text{ V}$.
- C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

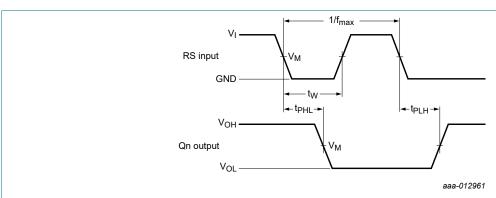
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

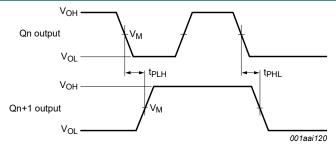
11.1. Waveforms and test circuit



Measurement points are given in <u>Table 7</u>.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 6. Waveforms showing the clock (RS) to output (Qn) propagation delays, the clock pulse width, the output transition times and the maximum frequency

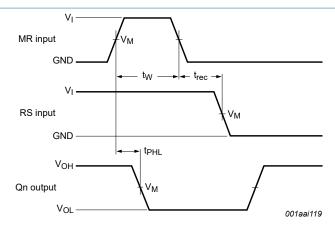


Measurement points are given in Table 7.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Waveforms showing the output Qn to output Qn+1 propagation delays Fig. 7.

14-stage binary ripple counter with oscillator



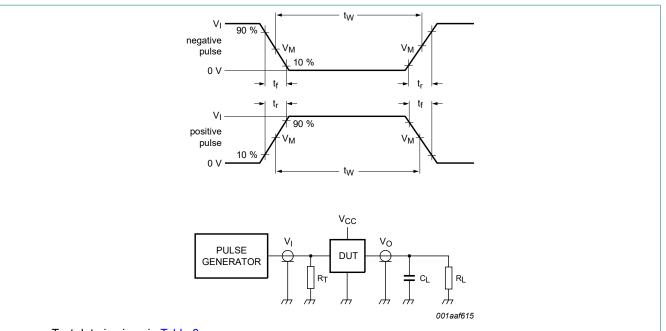
Measurement points are given in Table 7.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 8. Waveforms showing the master reset (MR) pulse width, the master reset to output (Qn) propagation delays and the master reset to clock (RS) recovery time

Table 7. Measurement points

Supply voltage	Input	Output		
V _{CC}	V _M	V _M		
< 2.7 V	0.5V _{CC}	0.5V _{CC}		
2.7 V to 3.6 V	1.5 V	1.5 V		
≥ 4.5 V	0.5V _{CC}	0.5V _{CC}		



Test data is given in Table 8.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

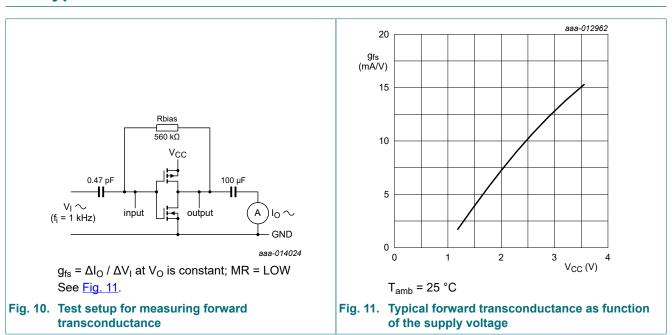
Fig. 9. Test circuit for measuring switching times

14-stage binary ripple counter with oscillator

Table 8. Test data

Supply voltage	ply voltage Input		Load			
V _{CC}	VI	t _r , t _f	CL	R _L		
V _{CC} < 2.7 V	V _{CC}	2.5 ns	50 pF	1 kΩ		
2.7 V < V _{CC} < 3.6 V	2.7 V	2.5 ns	15 pF, 50 pF	1 kΩ		
V _{CC} ≥ 4.5 V	V _{CC}	2.5 ns	50 pF	1 kΩ		

12. Typical forward transconductance

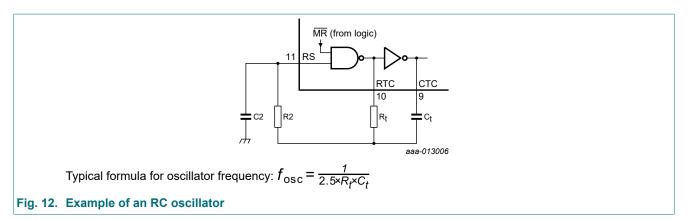


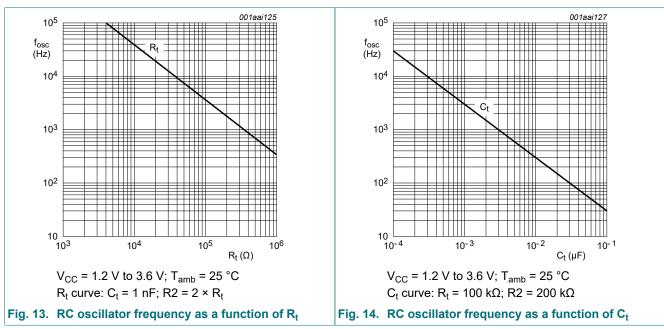
13. RC oscillator

13.1. Timing component limitations

The oscillator frequency is mainly determined by $R_t \times C_t$, provided $R2 \approx 2R_t$ and $R2 \times C2$ is much less than $R_t \times C_t$. The function of R2 is to minimize the influence of the forward voltage across the input protection diodes on the frequency. The stray capacitance C2 should be kept as small as possible. In consideration of accuracy, C_t must be larger than the inherent stray capacitance. R_t must be larger than the 'ON' resistance in series with it, which typically is $280~\Omega$ at $V_{CC} = 1.2~V$, $130~\Omega$ at $V_{CC} = 2.0~V$ and $100~\Omega$ at $V_{CC} = 3.0~V$. The recommended values for these components to maintain agreement with the typical oscillation formula are: $C_t > 50~pF$, up to any practical value, $10~k\Omega < R_t < 1~k\Omega$. In order to avoid start-up problems, $R_t \ge 1~k\Omega$.

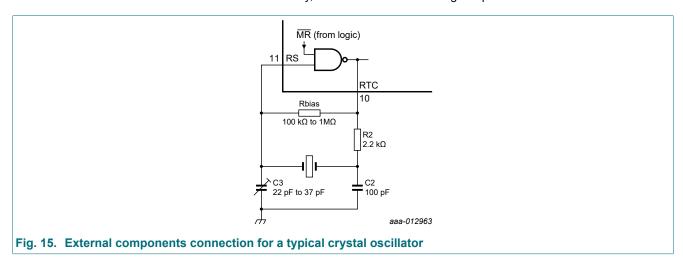
14-stage binary ripple counter with oscillator





13.2. Typical crystal oscillator circuit

In Fig. 15, R2 is the power limiting resistor. For starting and maintaining oscillation, a minimum transconductance is necessary, so R2 must not be too large. A practical value for R2 is $2.2 \, k\Omega$.



14-stage binary ripple counter with oscillator

14. Package outline

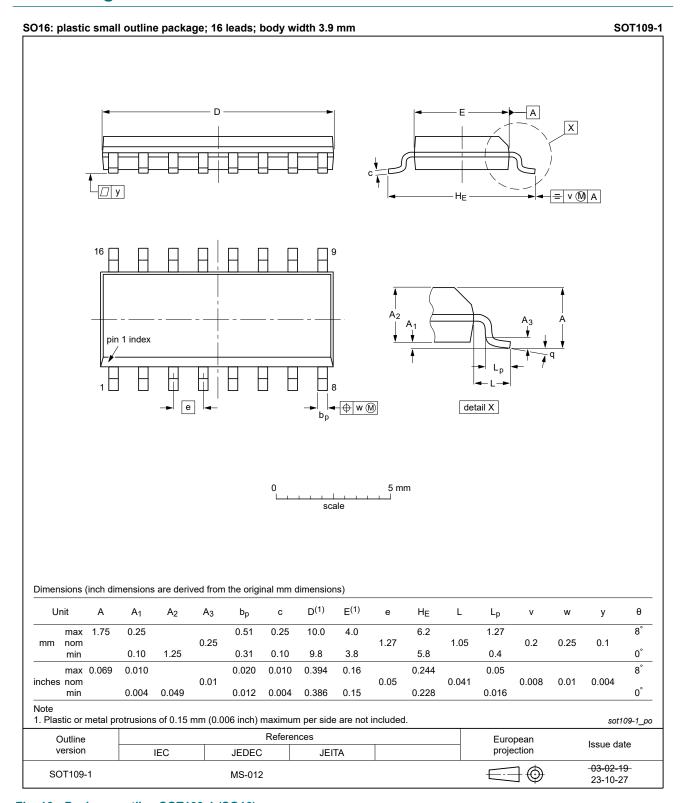


Fig. 16. Package outline SOT109-1 (SO16)

14-stage binary ripple counter with oscillator

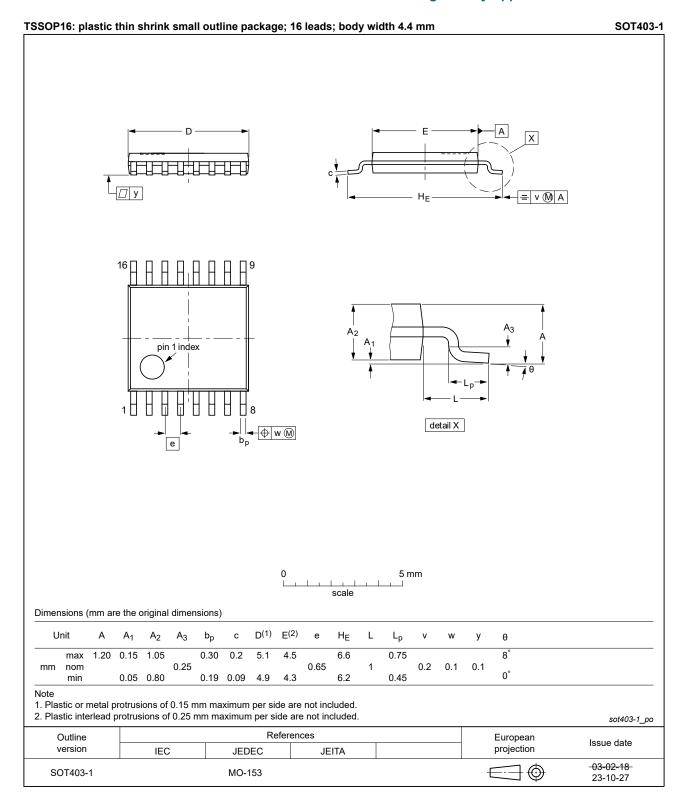


Fig. 17. Package outline SOT403-1 (TSSOP16)

14-stage binary ripple counter with oscillator

15. Abbreviations

Table 9. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

16. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LV4060 v.6	20240416	Product data sheet	-	74LV4060 v.5	
Modifications:	 <u>Section 2</u>: ESD specification updated according to the latest JEDEC standard. <u>Section 14</u>: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153 				
74LV4060 v.5	20210324	Product data sheet	-	74LV4060 v.4	
Modifications:	Nexperia. Legal texts ha Section 1 and Section 8: Der	this data sheet has been redes ve been adapted to the new co Section 2 updated. rating values for P _{tot} total powe 74LV4060DB (SOT338-1/SSO	ompany name where	appropriate.	
74LV4060 v.4	20160317	Product data sheet	-	74LV4060 v.3	
Modifications:	Type number 74LV4060N (SOT38-4) removed.				
74LV4060 v.3	20140728	Product data sheet	-	74LV4060 v.2	
Modifications:	Minimum value V _{OH} and V _{OL} corrected (errata).				
74LV4060 v.2	20140703	Product data sheet	-	74LV4060 v.1	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74LV4060 v.1	19980623	Product specification	-	-	

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

14-stage binary ripple counter with oscillator

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

74LV4060

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2024. All rights reserved

14-stage binary ripple counter with oscillator

Contents

1. G	eneral description	1
2. Fe	eatures and benefits	. 1
3. A	pplications	. 1
4. O	rdering information	1
5. Fu	unctional diagram	2
6. Pi	inning information	3
6.1.	Pinning	3
6.2.	Pin description	3
7. Fu	unctional description	4
8. Li	miting values	. 4
	ecommended operating conditions	
10. 5	Static characteristics	5
11. [Oynamic characteristics	8
11.1.	Waveforms and test circuit	. 9
12. T	Typical forward transconductance	11
13. F	RC oscillator	11
13.1.	Timing component limitations	11
13.2.	Typical crystal oscillator circuit	12
14. F	Package outline	13
15. <i>A</i>	Abbreviations	15
16. F	Revision history	15
17. L	_egal information	16

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 16 April 2024

[©] Nexperia B.V. 2024. All rights reserved